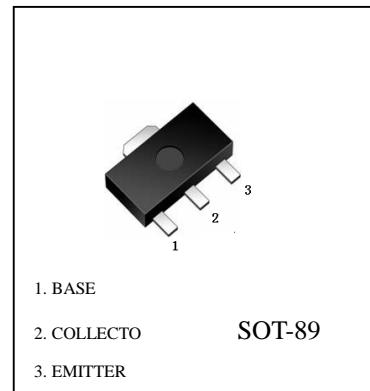


FEATURES

- Low saturation voltage, typically VCE (sat) =0.1V at IC/IB =1A /50mA.
- Excellent DC current gain characteristics.
- Complements the 2SA1797.

2SC4672 (NPN)



Maximum Ratings (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current -Continuous	I _C	2	A
Collector Power dissipation	P _C	0.5	W
Storage Temperature	T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@ Ta=25 °C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{CBO}	I _C =50μA,I _B =0	60			V
Collector-emitter breakdown voltage	V _{CEO}	I _C =1mA,I _B =0	50			V
Emitter-base breakdown voltage	V _{EBO}	I _E =50μA,I _C =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =60V,I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _C =0			0.1	μA
DC current gain	h _{FE}	V _{CE} =2V,I _C =0.5A	82		270	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =1A,I _B =50mA			0.35	V
Transition frequency	f _T	V _{CE} =2V,I _C =500mA,f=100MHz		210		MHz
Collector output capacitance	C _{ob}	V _{CB} =10V,I _E =0,f=1MHz		25		pF

CLASSIFICATION OF h_{FE}

Rank	P	Q
Range	80-180	120-270
Marking	KDP	DKQ

2SC4672 Typical Characteristics

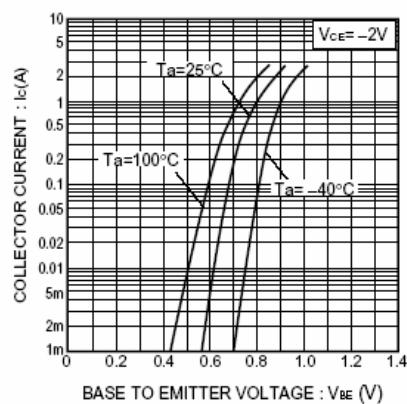


Fig.1 Grounded emitter propagation characteristics

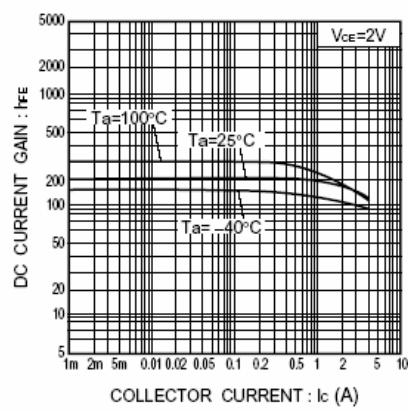


Fig.2 DC current gain vs. collector current

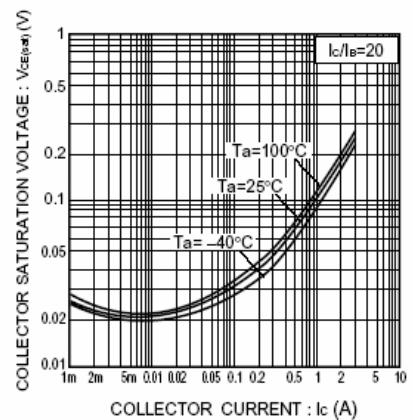
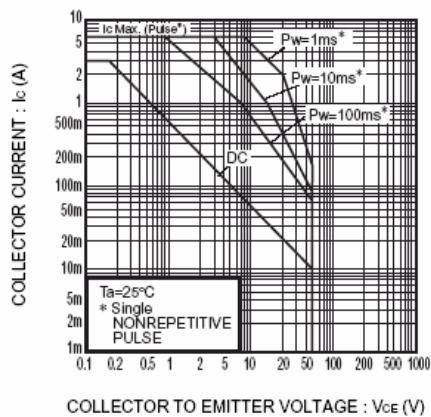


Fig.3 Collector-emitter saturation voltage vs. collector current



COLLECTOR TO EMITTER VOLTAGE : V_{CE} (V)

Fig.4 Safe Operating area